Green SrSi$_2$O$_2$N$_2$:Eu$^{2+}$ phosphor for LED-phosphor applications: synthesis and characterization

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**Article Info**

**Article history:**
Received Oct 27, 2022
Revised Nov 2, 2022
Accepted Jan 11, 2023

**Keywords:**
Color homogeneity
Double-layer phosphor
Luminous flux
SrSi$_2$O$_2$N$_2$:Eu$^{2+}$
WLEDs

**ABSTRACT**

Green phosphors SrSi$_2$O$_2$N$_2$:Eu$^{2+}$ (SSON:Eu) are combined utilizing a simple solid-state reaction with SrSi$_2$O$_2$N$_2$:Eu$^{2+}$ like the forerunner. Various phosphor attributes were assessed following creation procedure. Differential thermal analysis (DTA) spectra and luminescence measurements are used to assess crystalline active power, electron-phonon conjunction, and heat quenching behavior. Because of their poor electron-phonon conjunction intensity (Huang-Rhys factor=4.2), SSON:Eu green phosphors have outstanding heating and color consistency. The heat quenching temperature ($T_{50}$) of SSON:Eu is greater than 200 °C. SSON:Eu green phosphors have a wide stimulation range, strong heat steadiness and can absorb ultraviolet (UV) to blue energy and release green illumination, leading to the appropriate utilization in solid-state illumination and GaAsAl solar cells, according to the findings.

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1. **INTRODUCTION**

Phosphors are commonly employed in high-performance implementations such as phosphor-transformed illumination-releasing diodes light-emitting diodes (LEDs), liquid crystal display backlights, and solar-cell panels [1], [2]. Since they imbibe close-ultraviolet (UV) or blue illumination (380–470 nm) from LEDs and generate sufficient viewable illumination in regularly utilized sulfide, silicate, or oxynitride/nitride host substances, Eu$^{2+}$-doped phosphors are widely utilized in LEDs [3], [4]. As a result, transformation phosphors must have a broad stimulation band that encompasses this range of wavelength. Oxynitride phosphors, like Ca-SiAlON: Eu$^{2+}$, SSON:Eu, and CaSi$_2$O$_2$N$_2$: Eu$^{2+}$, have lately received much interest because they have great chemical steadiness and no toxicity [5]. They have substantial absorptivity between the close-UV and blue illumination spectrum, which exactly matches the supplied illumination of mercantile LEDs, helping them to be suitable choices for white LEDs (WLED’s). Nevertheless, the synthesizing requirements for oxynitride-based phosphors are extremely stringent, necessitating elevated temperatures and elevated $N_2$ tension. According to this paper, a normal-pressure sintering process is offered to produce SSON:Eu phosphors from Sr$_3$SiO$_2$:Eu$^{2+}$ like a forerunner. Computing the activation energy of crystallization yields the reaction mechanism. SSON:Eu phosphors have earlier been examined, however just the luminescence and configuration characteristics were described [6], [7]. Research by Durmus and Davis [8] found that the heat quenching temperature of SSON:Eu is around 600 K. (327 °C). Low crystallization activating energy for substance synthesizing methods suggests that the synthesizing technique is straightforward to conduct [9], [10]; also the compounds having great crystallization may be
generated. Phosphors having high crystallization will also include a high luminosity. As a result, we can utilize the crystallization activation energy to specify the best combination technique. In [11] and [12] found the crystallized activating power of glass ceramics with silicate/oxynitride base around ~400 and 834 kJ/mol, correspondingly, utilizing a distinctive heating study differential thermal analysis (DTA). The SSON:Eu phosphors’ crystallized activating power are determined in this study. Also explored are the electron-phonon linking intensity, heat steadiness, and hue consistency of SSON:Eu phosphors. Further data on the phosphor samples will be discussed in sections 2 and 3 which concern the computation of phosphor attributes and the assessment of phosphor influence on WLED’s factors. The findings demonstrate that the phosphors’ wide band-type stimulation and emission are ideal for solid-state illumination and solar cell uses, as shown in sections 4.

2. COMPUTATIONAL SIMULATION

SSON:Eu specimens were produced in a one-stage and two-stage solid-state synthesis, accordingly. For the sole-stage combination technique (I) (specimen I), the initial substances, having 99.9% purity, includes SrCO₃, SiO₂, Eu₂O₃, and α-Si₃N₄. We combine them by pulverizing and sintering in one horizontal pipe furnace under 1,450 °C within 6 hours below decreasing environment (5% H₂–95% N₂). A combination including SrCO₃, SiO₂, and Eu₂O₃ was burned underneath a decreasing environment at 1250 °C within 3 hours for creating Sr₃SiO₄Eu₂⁺ specimens for the two-stage synthesis method (II) (specimen II). The SrSiO₄Eu₂⁺ specimen and Si₃N₄ combination were then burned once more at 1,450 °C for 6 hours within the similar decreasing environment for obtaining SSON:Eu phosphors [13], [14].

One of the most commonly utilized techniques in crystallization kinetic investigations is the Kissinger technique. We utilize the Kissinger equation to calculate the crystallized activating power [15]:

\[ \ln\left(\frac{\Phi}{T_p^2}\right) = \frac{-E_c}{RT_p} + c \quad (c=constant) \]  

(1)

Where \( \Phi \) denotes the DTA scan ratio (°C/min), \( T_p \) denotes the highest DTA crystallized highest heat (K), and \( R = 8.3144 \) J/mol K and represents the gas constant. \( E_c \) represents the crystallized activating power, calculated relying to the slope of the \( \ln\left(\frac{\Phi}{T_p^2}\right) \) vs. \( 10^3/RT_p \) plot. The temperature dependence of luminous strength can be described using the Arrhenius [15]:

\[ I(T) = \frac{I_0}{1 + c \exp\left(\frac{-\Delta E}{kT}\right)} \]  

(2)

A and C represent constant factors, k represents Boltzmann's constant, \( I_0 \) denotes the starting strength, \( I(T) \) denotes the strength at the provided heat T, and \( \Delta E \) denotes the activating power for the heat extinguishing phase, calculated according to the slope for \( \ln[I(T)] - 1 \) vs. \( 1/KT \) plot. A smaller \( \Delta E \) scope indicates a faster non-radiation ratio with a provided heat. The emission spectra's full width half maximum (FWHM) (T) can be explained through utilizing the configurational coordinate design as well as Boltzmann [16] dispensation as:

\[ FWHM(T) = h\nu[8 \times \ln 2 \times S \times \coth(\frac{h\nu}{2kBT})]^{1/2} \]  

(3)

Where \( h\nu \) represents the medium phonon power. S represents the Huang-Rhys number. kB represents the Boltzmann constant. The electron-phonon coupling strength is represented by the Huang-Rhys parameter S. If S<1, the linking is faint; if 1<S<5, the coupling is mean; and if S>5, the coupling is potent. Dorenbos [17] defined this relationship as (4):

\[ FWHM(T) = h\nu[8 \times \ln 2 \times S \times \coth(\frac{h\nu}{2kBT})]^{1/2} \]  

(4)

Where \( E_{inc}=4.19e \) V and represents the power variation regarding gaseous-state Eu²⁺ ions, and D denotes the redshift power reduction.

3. RESULTS AND DISCUSSION

The demand for stable and effective phosphors in the red region of the emission spectrum, which oxides cannot easily offer, stimulated research in various phosphor base types having a large crystal field and/or a big centroid shift. It is obvious that the extensive-band emitting rare-earth ions like Eu²⁺ as well as Ce³⁺ have virtually optimal characteristics; the remaining issue is to identify acceptable hosts with a large enough redshift. This property was discovered in (oxy)nitride phosphors, prompting a significant investigation into this novel class of materials throughout the last decade. Generally, (oxy)nitride phosphors have outweighed other phosphors in terms of thermal and chemical stabilities. They were also studied for

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their outstanding thermal and chemical stability, strength, and hardness, making them appropriate for abrasives and protective coatings. Nevertheless, previous studies did not examine much about their luminescent characteristics. Additionally, the stability examinations for oxidation or the photo-thermal influence of LED’s large fluxes were barely reported. The next section will demonstrate the influence simulation of SSON:Eu on the WLED luminescence and color characteristics.

Figure 1 illustrates the inverse variation for SSON:Eu as well as YAG:Ce³⁺ phosphor presence regarding three correlated color temperature (CCT) of 3,000 K (Figure 1(a)), 4,000 K (Figure 1(b)), and 5,000 K (Figure 1(c)). Two implications are made by such shift: the first is to keep mean CCTs stable, and the second is to impact absorbance and dispersion in the phosphor-layer structure of WLEDs. As light absorbance and dispersion are impacted, the chroma adequacy along with luminous flux in the WLED apparatus are also modified. As such, the SSON:Eu concentration alters the color quality of WLEDs. The YAG:Ce³⁺ concentration dropped as the SSON:Eu concentration climbed from 2 to 20% by weight for preserving the average CCTs (5,600-8,500 K) [18].

![Figure 1](image1.png)

**Figure 1.** Varying concentrations for phosphors to retain the stable CCT (a) 3,000 K, (b) 4,000 K, and (c) 5,000 K

Figure 2 shows the SSON:Eu presence’s impact on the WLED’s transmitting spectra observed at 3,000 K (Figure 2(a)), 4,000 K (Figure 2(b)), and 5,000 K (Figure 2(c)). By observing the change in the strength of emission in certain wavelengths, in connection with the change in green phosphor concentration, we can possibly find out the suitable to obtain high lumen for WLEDs [19], [20]. As shown in the data, the emission bands are obvious in 420-480 nm along with 500-640 nm wavelength zones. Moreover, the peaks in these two emission wavelength bands are at ~420 and ~505 nm, meaning that the blue and green emissions are stronger. This benefits the luminance power of the WLED. So, it means that SSON:Eu could notably improve emissions strengths or luminescence of the white light from LEDs. The results in Figure 3 are used to re-confirm the enhancement in the luminosity of WLEDs when applying the SSON:Eu phosphor. At all three CCTs, 3,000 K (Figure 3(a)), 4,000 K (Figure 3(b)), and 5,000 K (Figure 3(c)), the luminous flux emitted grows dramatically when the SSON:Eu proportion grows in the range 2-20% wt.

Besides the luminosity, the angular divergence on the chroma scale was dramatically reduced with the phosphor SSON:Eu proportion in three average CCTs, based on the results in Figure 4, exhibiting CCT levels of 3,000 K (Figure 4(a)), 4,000 K (Figure 4(b)), and 5,000 K (Figure 4(c)). This is because of the enhanced dispersion of blue illumination and the absorptivity of the green-phosphor SSON:Eu. When phosphor SSON:Eu was integrated, blue emission was enhanced (see Figures 2(a)-(c)), improving the probability of blue-light scattering and dispersing inside the WLED structure. Then, every time the blue light encounters the green phosphor particle, it is absorbed easily. The green phosphor subsequently emits the green illumination through the down-conversion process. Though the yellow light is absorbed by SSON:Eu granules, it is just a smaller amount, compared to that of the blue light. With the enhanced dispersion and supplemented green light, the color divergence is reduced for the enhancement of color uniformity [21], [22]. Obviously, color uniformity is an important feature of high-quality WLED, and so does the luminosity. Thus, the concentration of SSON:Eu should be selected based on the application requirements, whether it requires to have high-color-quality WLED or high-luminescence WLED. The WLED with high color quality could emit a relatively weaker luminescence. Besides, the better the chromatic consistency index, the more costly the WLED. Employing SSON:Eu only requires an inexpensive cost. SSON:Eu can therefore be broadly used.
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Hue quality cannot be claimed to be good when having only a good hue homogeneity indicator. It needs to consider other two factors, consisting of color rendition intent (CRI) and the preference of viewers’ visuality [23], [24]. Researchers have developed and used the color quality scale (CQS) to access these three important factors. The CRI is used to evaluate the real hue of a lightened object revealed by a tested light. The data recorded for CRI and CQS were shown in Figures 5 and 6. At all CCTs 3,000-5,000K (Figures 5(a)-(c)), CRI showed a small reduction when accompanied by a SSON:Eu sheet. In Figures 6(a)-(c), it is possible to observe how CQS is amplified when accompanied by the SSON:Eu film. On the other hand, if SSON:Eu concentrations are below 10% wt, CQS is hardly altered. If SSON:Eu concentrations are above 10% wt., CQS and also CRI significantly reduced because of severe hue imbalance when green is dominant over the other two main hues, blue and yellow [25]-[28]. WLED color accuracy is reduced as a result of this having an effect on the hue standard of WLEDs. Owing to that, an appropriate choice on SSON:Eu weight percentage is very necessary.

Figure 5. CRI in WLED device correlating with SSON:Eu presence (a) 3,000 K; (b) 4,000 K, and (c) 5,000 K

Figure 6. CQS in WLED device correlating with SSON:Eu presence (a) 3,000 K, (b) 4,000 K, and (c) 5,000 K

4. CONCLUSION
Green phosphors SSON:Eu produced from Sr₂SiO₄:Eu²⁺ exhibit small crystallized activating power (408.82 KJ/mol) and a low Huang-Rhys number (4.2). SSON:Eu has a heat quenching temperature (T₅₀) more than 200 °C. Because of their poor electron-phonon coupling strength, SSON:Eu demonstrates remarkable temperature and color stability. SSON:Eu phosphors absorb UV to blue energy and release green
illuminating, potentially improving the GaAs/Ga solar cells’ effectiveness. The findings suggest SSN:Eu green phosphors could be used in solid-state illumination and solar cells.

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